## NSN 5961-01-073-6074



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-073-6074 **Inclosure Material:** Metal **Overall Length:** Between 0.215 inches and 0.320 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-60 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 1.50 amperes source cutoff current and 4.50 amperes source cutoff current **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 49956-584448 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure:** 

Fiig: A110a0

No

**Demilitarization:**